

Form PTO-1449

Doc No. (Optional)

Application Number

TSMC-03-265

10/757,203

Applicant

Kuo-Chi Tu

Filing Date

01/14/04

Group Art Unit

INFORMATION DISCLOSURE CITATION  
IN AN APPLICATION.

(Use several sheets if necessary)

## U. S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILED DATE IF APPROPRIATE
Sm	6256248	7/3/01	Leung	365	222	6/9/00
Sm	6468855	10/22/02	Leung et al.	438	239	1/29/01
Sm	4713678	12/15/87	Womack et al.	357	23.6	11/13/86
Sm	6420226	7/16/02	Chen et al.	438	238	12/6/01
Sm	6580110	6/17/03	Schrems	257	301	4/12/01

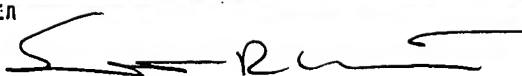
## FOREIGN PATENT DOCUMENTS

DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
					YES	NO

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

Sm -	"The Ideal SoC Memory: 1T-SRAM", Leung et al., pp.32-36, Proceedings of the IEEE 2000.

EXAMINER



DATE CONSIDERED

1-06-2005

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.